

International **ICR** Rectifier

10BQ100PbF

SCHOTTKY RECTIFIER

1 Amp

$I_{F(AV)} = 1.0\text{Amp}$
 $V_R = 100\text{V}$

Major Ratings and Characteristics

Characteristics	Value	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	100	V
I_{FSM} @ $t_p = 5\mu\text{s}$ sine	780	A
V_F @ 1.0Apk , $T_J = 125^\circ\text{C}$	0.62	V
T_J range	-55 to 175	$^\circ\text{C}$

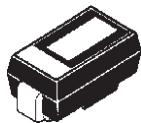
Description/ Features

The 10BQ100PbF surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)

Case Styles

10BQ100PbF



Cathode ————— Anode

SMB

Voltage Ratings

Part number	10BQ100PbF
V_R Max. DC Reverse Voltage (V)	100
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	10BQ	Units	Conditions	
$I_{F(AV)}$	Max. Average Forward Current	1.0	A	50% duty cycle @ $T_L = 152^\circ\text{C}$, rectangular wave form
I_{FSM}	Max. Peak One Cycle Non-Repetitive Surge Current	780		5μs Sine or 3μs Rect. pulse
		38		10ms Sine or 6ms Rect. pulse
E_{AS}	Non-Repetitive Avalanche Energy	1.0	mJ	$T_j = 25^\circ\text{C}$, $I_{AS} = 0.5\text{A}$, $L = 8\text{mH}$
I_{AR}	Repetitive Avalanche Current	0.5	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_j max. $V_a = 1.5 \times V_r$ typical

Electrical Specifications

Parameters		10BQ	Units	Conditions		
V_{FM}	Max. Forward Voltage Drop (1) * See Fig. 1	0.78	V	@ 1A	$T_J = 25^\circ C$	
		0.89	V	@ 2A		
		0.62	V	@ 1A	$T_J = 125^\circ C$	
		0.72	V	@ 2A		
I_{RM}	Max. Reverse Leakage Current (1) * See Fig. 2	0.5	mA	$T_J = 25^\circ C$	$V_R = \text{rated } V_R$	
		1	mA	$T_J = 125^\circ C$		
C_T	Typical Junction Capacitance	42	pF	$V_R = 5V_{DC}$ (test signal range 100kHz to 1MHz) $25^\circ C$		
L_S	Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body		
dv/dt	Max. Volatge Rate of Charge (Rated V_R)	10000	V/ μ s			

(1) Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters		10BQ	Units	Conditions
T_J	Max. Junction Temperature Range (*)	-55 to 175	°C	
T_{stg}	Max. Storage Temperature Range	-55 to 175	°C	
R_{thJL}	Max. Thermal Resistance Junction to Lead (**)	36	°C/W	DC operation
R_{thJA}	Max. Thermal Resistance Junction to Ambient	80	°C/W	
wt	Approximate Weight	0.10(0.003)	g(oz.)	
Case Style		SMB	Similar DO-214AA	
Device Marking		IR1J		

(*) $\frac{dP_{tot}}{dT_i} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

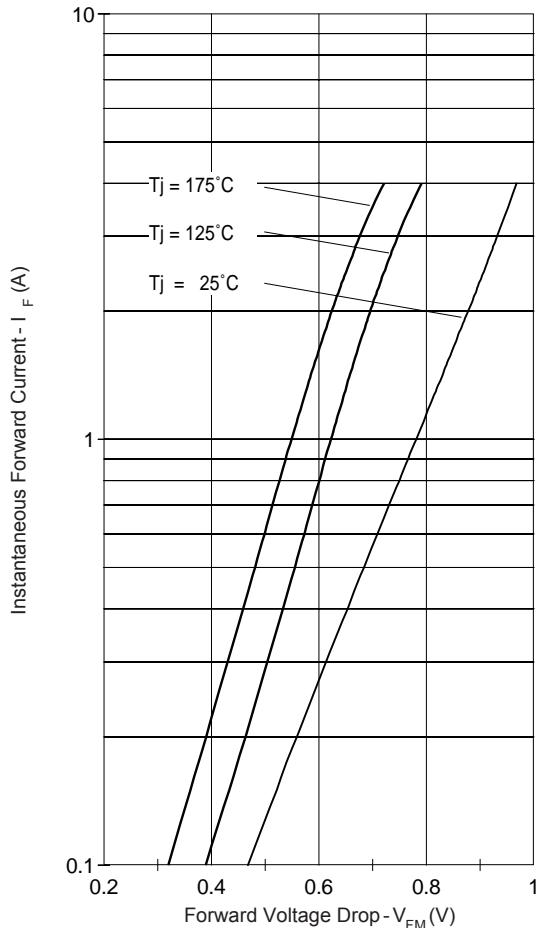


Fig. 1 - Maximum Forward Voltage Drop Characteristics

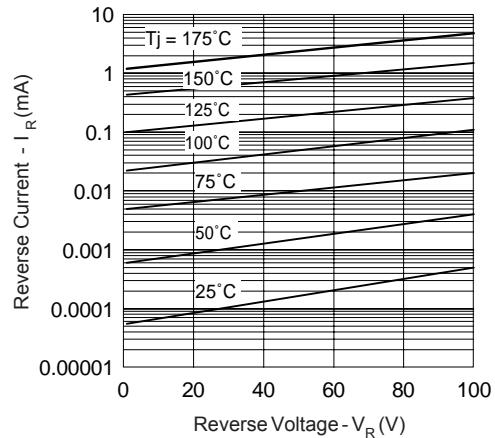


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

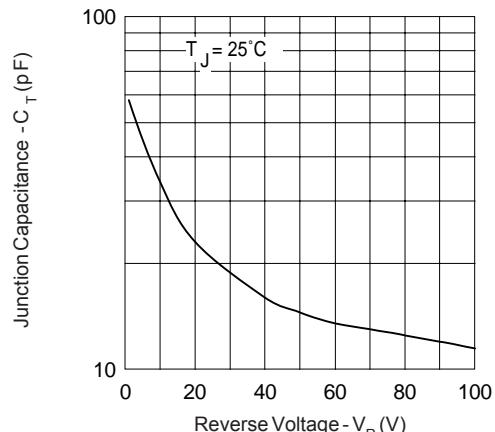


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

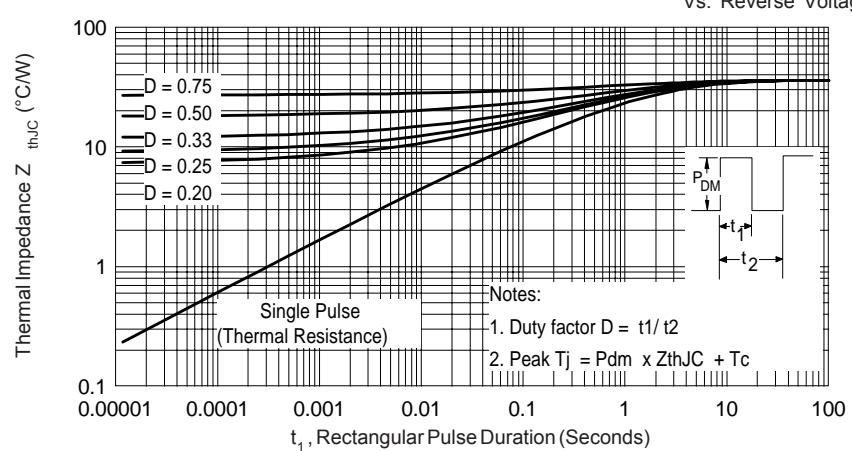


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

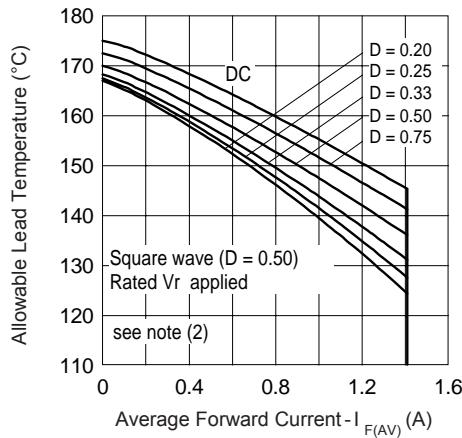


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

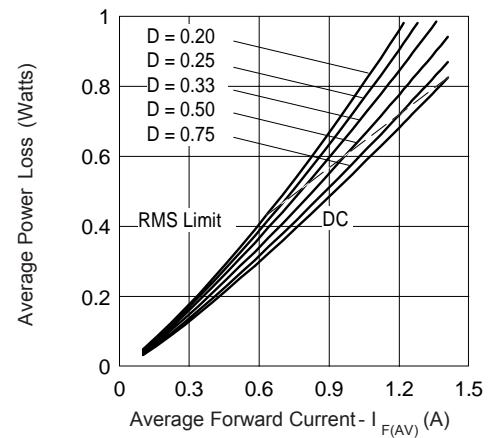


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

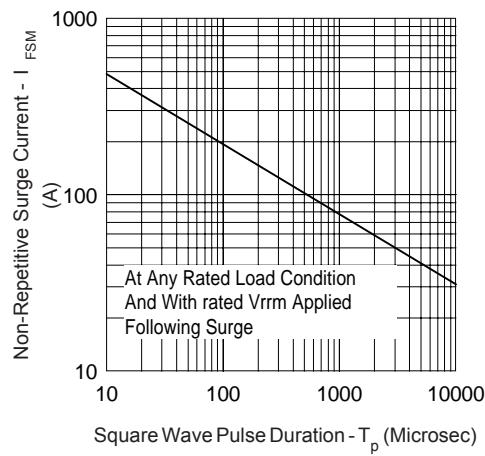
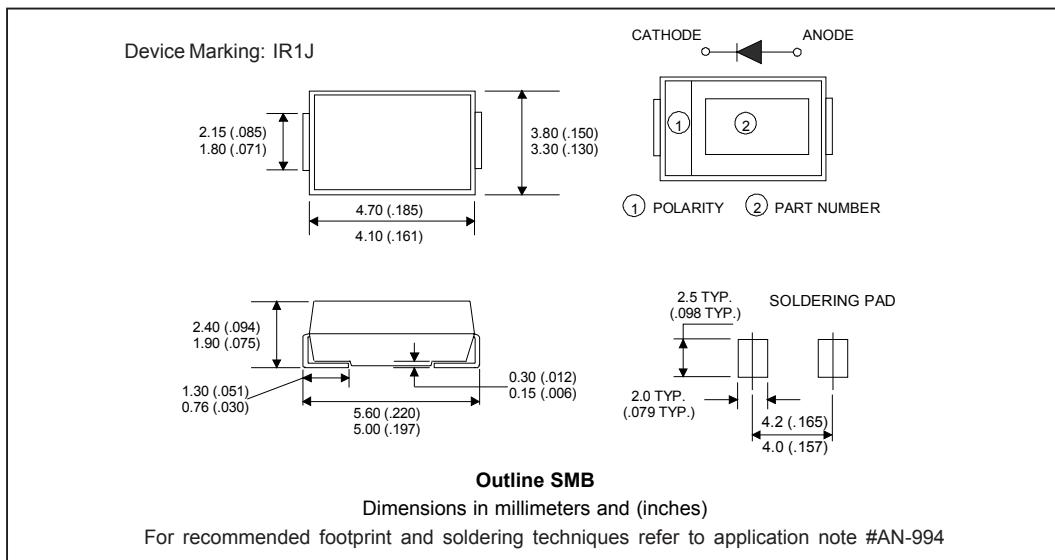


Fig. 6 - Maximum Peak Surge Forward Vs. Pulse Duration

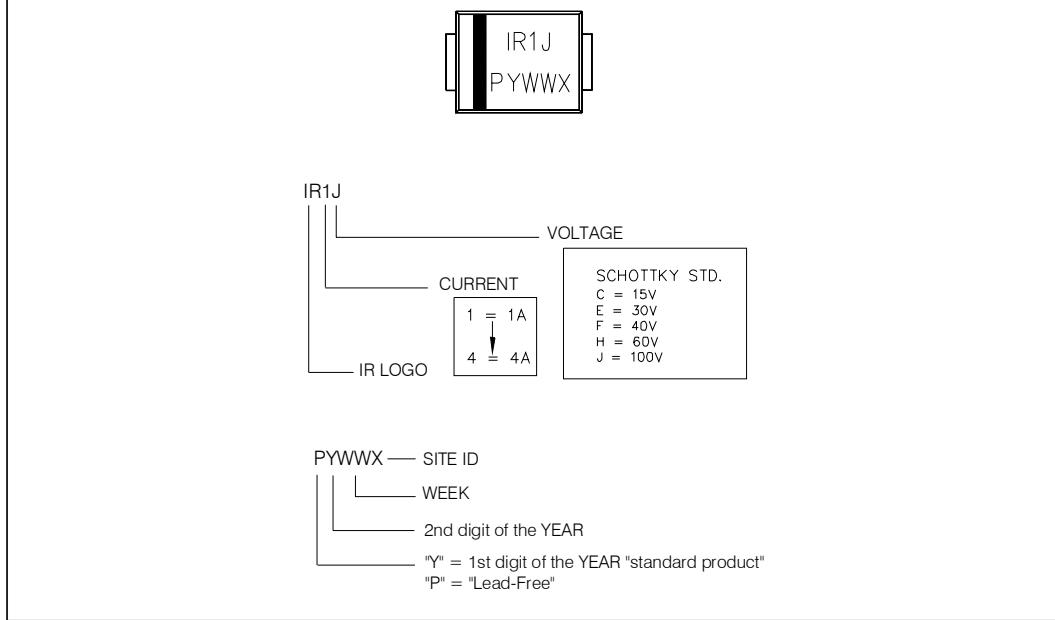
(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Outline Table

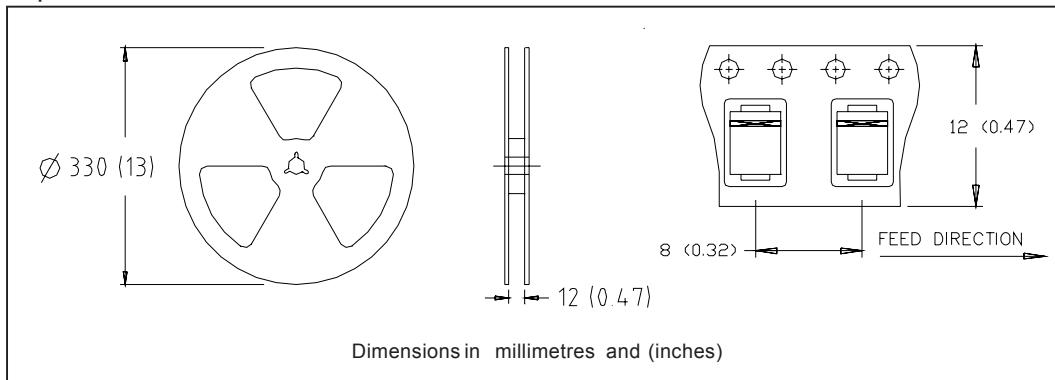


Marking & Identification

Each device has 2 rows for identification. The first row designates the device as manufactured by International Rectifier, indicated by the letters "IR", and the Part Number (indicates the current, the voltage rating and Schottky Generation). The second row indicates the year, the week of manufacturing and the Site ID.



Tape & Reel Information



Ordering Information Table

Device Code					
10	B	Q	100	TR	PbF
1					
1	- Current Rating				
2	- B = Single Lead Diode				
3	- Q = Schottky Q Series				
4	- Voltage Rating (100 = 100V)				
5	- • none = Box (1000 pieces)				
	• TR = Tape & Reel (3000 pieces)				
6	- • none = Standard Production				
	• PbF = Lead-Free				

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10BQ100
*****
* SPICE Model Diode
*****
.SUBCKT 10BQ100 ANO CAT
D1 ANO 1 CAT
*Define diode model
.model D10BQ100 D(Is=341.4E-06 N=2.664 Rs=3.65E-03 Ikf=37.08E-03 Xti=2 Eg=1.11
+ Cjo=65.57E-12 M=.5751 Vj=4.282 Fc=0.5 Isr=17.26E-27 Nr=5.662
+ Bv=119.9 Ibv=215.5E-06 Tt=43.28E-09)

*****
.ENDS 10BQ100
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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
07/04



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